

ELECTRICAL ODECIEICATIONS

Flammability

Solderability

Vibration

Gross Leak Test

Mechanical Shock

Moisture Resistance

Moisture Sensitivity

Temperature Cycling

Resistance to Soldering Heat Resistance to Solvents

ELECTRICAL SPECIFICATIONS		
Nominal Frequency	74.250MHz	
Frequency Tolerance/Stability	±25ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Ouput Load Change, First Year Aging at 25°C, Shock, and Vibration)	
Operating Temperature Range	-10°C to +70°C	
Supply Voltage	3.3Vdc ±10%	
Input Current	40mA Maximum	
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH=-8mA)	
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL=+8mA)	
Rise/Fall Time	3nSec Maximum (Measured at 20% to 80% of waveform)	
Duty Cycle	50 ±10(%) (Measured at 50% of waveform)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Pin 1 Connection	Tri-State (High Impedance)	
Tri-State Input Voltage (Vih and Vil)	+0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output (High Impedance)	
Standby Current	10µA Maximum (Disabled Output: High Impedance)	
RMS Phase Jitter	1pSec Maximum (12kHz to 20MHz offset frequency)	
Start Up Time	10mSec Maximum	
Storage Temperature Range	-55°C to +125°C	
ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 1, HBM: 1500V	
Fine Leak Test	MIL-STD-883, Method 1014, Condition A	

UL94-V0

MIL-STD-883, Method 1014, Condition C

MIL-STD-883, Method 2002, Condition B

MIL-STD-202, Method 210, Condition K

MIL-STD-883, Method 1010, Condition B

MIL-STD-883, Method 2007, Condition A

MIL-STD-883, Method 1004

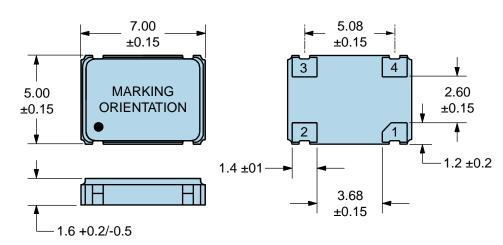
MIL-STD-202, Method 215

MIL-STD-883, Method 2003

J-STD-020, MSL 1

EC2625TS-74.250M TR

MECHANICAL DIMENSIONS (all dimensions in millimeters)

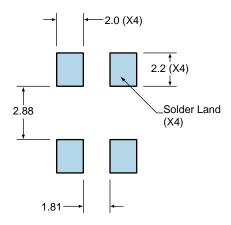


ECLIPTEK [®] CORPORATION				
PIN	CONNECTION			
1	Tri-State			
2	Ground/Case Ground			
3	Output			
4	Supply Voltage			
LINE	MARKING			

1	ECLIPTEK	
2	74.250M	
3	XXYZZ XX=Ecliptek Manufacturing Code Y=Last Digit of the Year ZZ=Week of the Year	

Suggested Solder Pad Layout

All Dimensions in Millimeters

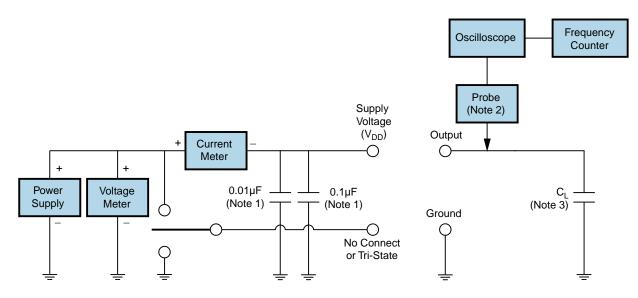


All Tolerances are ±0.1

EC2625TS-74.250M TR **OUTPUT WAVEFORM & TIMING DIAGRAM TRI-STATE INPUT** Ин VIL Vон CLOCK OUTPUT 80% of Waveform **OUTPUT DISABLE** 50% of Waveform (HIGH IMPEDANCE STATE) 20% of Waveform Vol **t**PLZ **t**PZL Fall Rise Time Time

Duty Cycle (%) = Tw/T x 100

Test Circuit for CMOS Output



Note 1: An external 0.1μ F low frequency tantalum bypass capacitor in parallel with a 0.01μ F high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

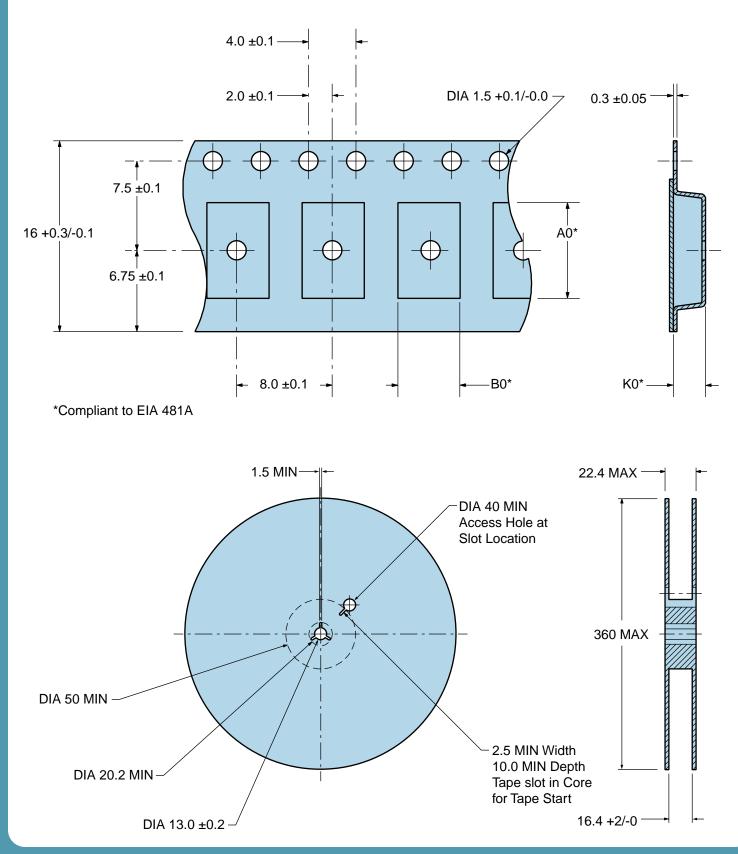
Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.

EC2625TS-74.250M TR



Tape & Reel Dimensions

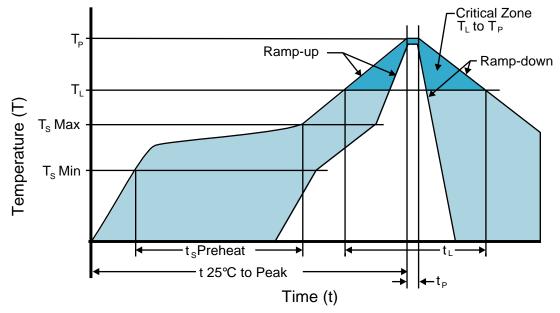
Quantity Per Reel: 1,000 units





Recommended Solder Reflow Methods

EC2625TS-74.250M TR



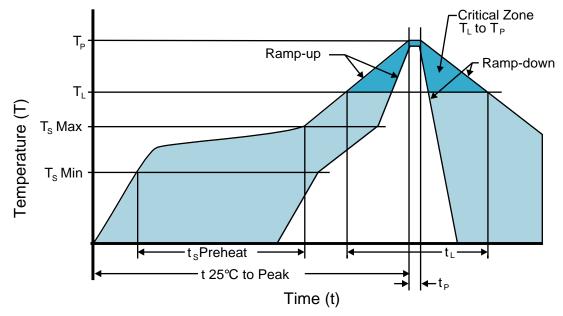
High Temperature Infrared/Convection

T _s MAX to T _L (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
 Temperature Maximum (T_s MAX) 	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T⊾ to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T⊾)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t _P)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.



Recommended Solder Reflow Methods

EC2625TS-74.250M TR



Low Temperature Infrared/Convection 240°C

T _s MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T⊾ to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t _p)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1
Additional Notes	Temperatures shown are applied to body of device.

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)